WNSC5D06650D



#### Silicon Carbide Diode Rev.01 - 10 October 2022

**Product data sheet** 

### **1. General description**

Silicon Carbide Schottky diode in a TO252 (DPAK) plastic package, designed for high frequency switched-mode power supplies.



## 2. Features and benefits

- Highly stable switching performance
- · Extremely fast reverse recovery time
- Superior in efficiency to Silicon Diode alternatives
- Reduced losses in associated MOSFET
- Reduced EMI
- Reduced cooling requirements
- RoHS compliant

## **3. Applications**

- Power factor correction
  - Telecom / Server SMPS
- UPS
- PV inverter
- PC Silverbox
- LED / OLED TV
- Motor Drives

## 4. Quick reference data

Table 1. Q	uick reference data						
Symbol	Parameter	Conditions	Notes	Values			Unit
Absolute	maximum rating						
$V_{\text{RRM}}$	repetitive peak reverse voltage				650		V
$I_{F(AV)}$	average forward current	δ = 0.5 ; square-wave pulse; T <sub>mb</sub> ≤ 141 °C; Fig. 1; Fig. 2; Fig. 3		6		A	
$T_{j}$	junction temperature			-55 to 175		°C	
Symbol	Parameter	Conditions	Notes	Min Typ Max		Unit	
Static ch	aracteristics						
V <sub>F</sub>	forward voltage	I <sub>F</sub> = 6 A; T <sub>j</sub> = 25 °C; <u>Fig. 5</u>		-	1.45	1.70	V
		I <sub>F</sub> = 6 A; T <sub>j</sub> = 150 °C; <u>Fig. 5</u>		-	1.80	2.20	V
Dynamic	characteristics						
Q <sub>r</sub>	recovered charge	I <sub>F</sub> = 6 A; dI <sub>F</sub> /dt = 500 A/μs; V <sub>R</sub> = 400 V; T <sub>j</sub> = 25 °C; <u>Fig. 7</u>		-	9	-	nC

# **5. Pinning information**

Pin	Symbol	Description	Simplified outline	Graphic symbol
1	n.c.	not connected		
2	K	cathode [1]		K <u>– – A</u> 001aaa020
3	A	anode	[]	
mb ł	К	mounting base; connected to cathode		

[1] It is not possible to connect to pin 2 of the TO252 package.

# 6. Ordering information

Table 3. Ordering information								
Type number	Package name	Orderable part number	Packing method	Small packing quantity	Package version	Package issue date		
WNSC5D06650D	TO252	WNSC5D06650D6J	Reel	2500	TO252NS	14-Nov-2016		

# 7. Marking

Table 4. Marking codes	
Type number	Marking codes
WNSC5D06650D	WNSC5D
	06650D

5aek3-002

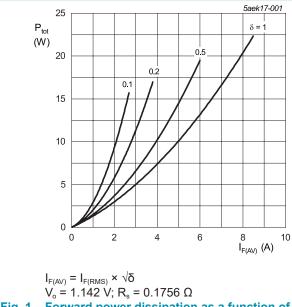
# 8. Limiting values

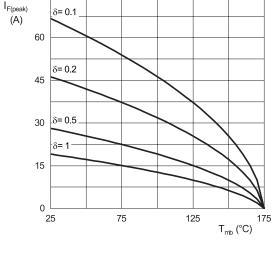
#### Table 5. Limiting values

In accordance with the Absolute Maximum Rating System (IEC 60134).

Symbol	Parameter	Conditions	Notes	Values	Unit
$V_{RRM}$	repetitive peak reverse voltage			650	V
V <sub>RWM</sub>	crest working reverse voltage			650	V
V <sub>R</sub>	reverse voltage	DC		650	V
I <sub>F(AV)</sub>	average forward current	δ = 0.5; square-wave pulse; T <sub>mb</sub> ≤ 141 °C; Fig. 1; Fig. 2; Fig. 3		6	A
I <sub>FRM</sub>	repetitive peak forward current	δ = 0.5; t <sub>p</sub> = 25 μs; T <sub>mb</sub> ≤ 141 °C; square-wave pulse		12	A
I <sub>FSM</sub>	non-repetitive peak	$t_p$ = 10 ms; $T_{j(init)}$ = 25 °C; sine-wave pulse		36	А
	forward current	$t_p$ = 10 µs; $T_{j(init)}$ = 25 °C; square-wave pulse		350	А
l <sup>2</sup> t	I <sup>2</sup> t for fusing	sine-wave pulse; $T_{j(init)}$ = 25 °C; $t_p$ = 10 ms		6.48	A <sup>2</sup> s
T <sub>stg</sub>	storage temperature			-55 to 175	°C
Tj	junction temperature			-55 to 175	°C

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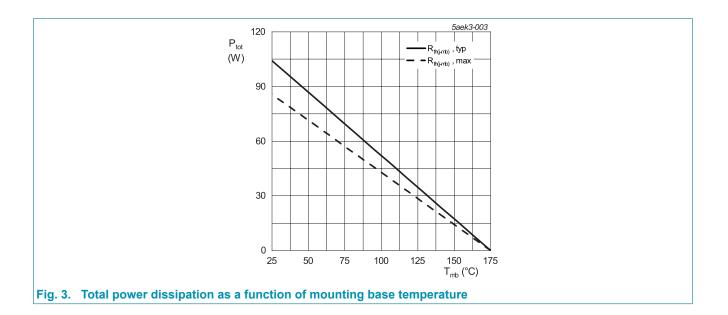






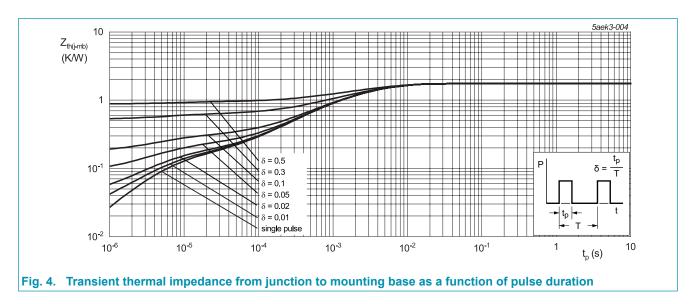
	$V_{o} = 1.142 \text{ V}; \text{ R}_{s} = 0.1756 \Omega$
Fig. 1.	Forward power dissipation as a function of average forward current; square waveform;
	maximum values

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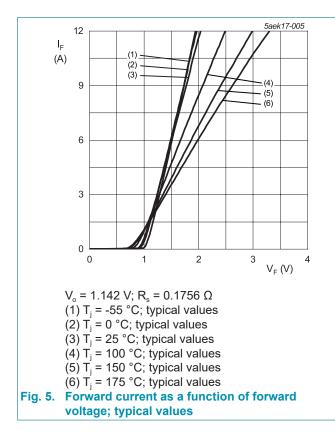
# 9. Thermal characteristics

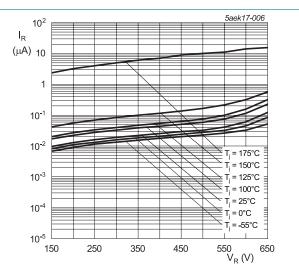
Symbol	Parameter	Conditions	Notes	Min	Тур	Max	Unit
$R_{th(j-mb)}$	thermal resistance from junction to mounting base	with heatsink compound; Fig. 4		-	1.44	1.75	K/W
R <sub>th(j-a)</sub>	thermal resistance from junction to ambient free air	in free air		-	50	-	K/W



## **10. Characteristics**

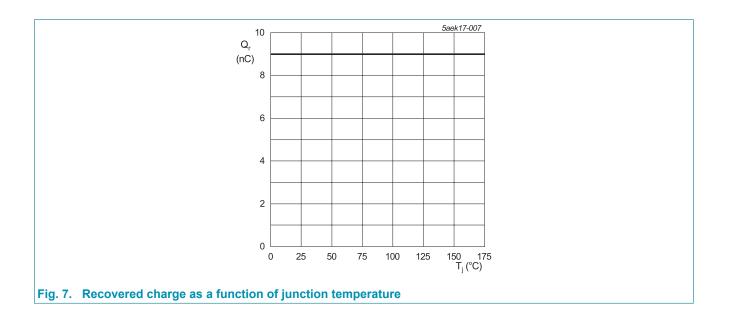
Symbol	Parameter	Conditions	Notes	Min	Тур	Max	Unit
Static cha	racteristics						
V <sub>F</sub>	forward current	I <sub>F</sub> = 6 A; T <sub>j</sub> = 25 °C; <u>Fig. 5</u>		-	1.45	1.70	V
		I <sub>F</sub> = 6 A; T <sub>j</sub> = 150 °C; <u>Fig. 5</u>		-	1.80	2.20	V
		I <sub>F</sub> = 6 A; T <sub>j</sub> = 175 °C; <u>Fig. 5</u>		-	2.00	2.30	V
I <sub>R</sub>	reverse current	V <sub>R</sub> = 650 V; T <sub>j</sub> = 25 °C; <u>Fig. 6</u>		-	0.3	30	μA
		V <sub>R</sub> = 650 V; T <sub>j</sub> = 175 °C; <u>Fig. 6</u>		-	15	150	μA
Dynamic	characteristics					_	
Q <sub>r</sub>	recovered charge	$I_F = 6 \text{ A}; V_R = 400 \text{ V}; \text{ d}_F/\text{dt} = 500 \text{ A}/\mu\text{s};$ $T_j = 25 \text{ °C}; Fig. 7$		-	9	-	nC
C <sub>d</sub>	diode capacitance	f = 1 MHz; V <sub>R</sub> = 1 V; T <sub>j</sub> = 25 °C		-	201	-	pF
		f = 1 MHz; V <sub>R</sub> = 300 V; T <sub>j</sub> = 25 °C		-	24	-	pF
		f = 1 MHz; V <sub>R</sub> = 600 V; T <sub>j</sub> = 25 °C		-	22	-	pF
E <sub>as</sub>	non-repetitive avalanche energy	I <sub>R</sub> = 3.5 A; L = 5 mH; T <sub>j(init)</sub> = 25 °C		30	-	-	mJ



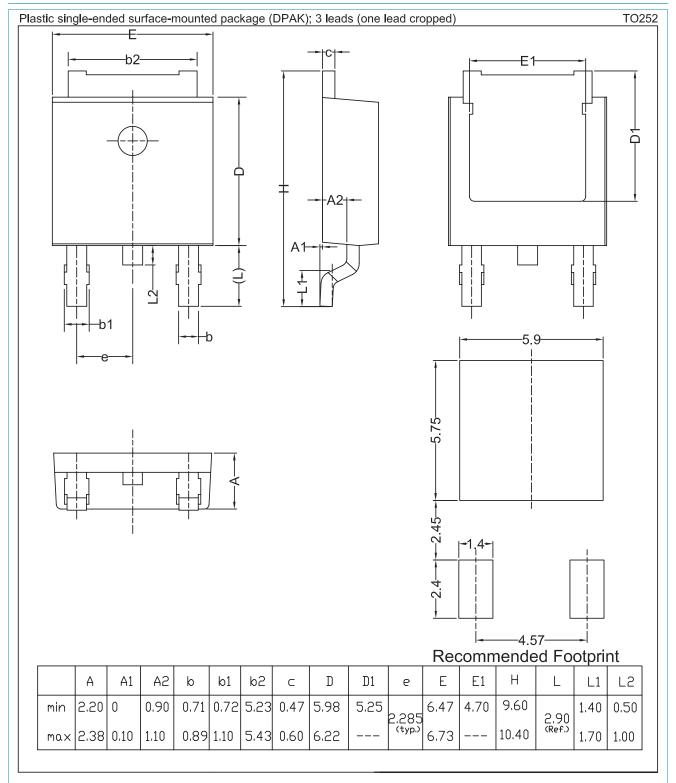




### **WeEn Semiconductors**



## **11. Package outline**



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# 12. Legal information

#### Data sheet status

Document status [1][2]	Product status [3]	Definition
Objective [short] data sheet	Development	This document contains data from the objective specification for product development.
Preliminary [short] data sheet	Qualification	This document contains data from the preliminary specification.
Product [short] data sheet	Production	This document contains the product specification.

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